

FJB5555 NPN Silicon Transistor

Features

- High Voltage Switch Mode Application
- Fast Speed Switching
- Wide Safe Operating Area
- Suitable for Electronic Ballast Application



1.Base 2.Collector 3.Emitter

Symbol	Parameter	Value	Units
BV _{CBO}	Collector-Base Voltage	1050	V
BV _{CEO}	Collector-Emitter Voltage	400	V
BV _{EBO}	Emitter-Base Voltage	14	V
۱ _C	Collector Current (DC)	5	А
I _{CP}	Collector Current (Pulse)	10	A
I _B	Base Current (DC)	2	А
I _{BP}	Collector Current (Pulse)	4	A
TJ	Junction Temperature	150	°C
T _{STG}	Storage Junction Temperature Range	- 55 to 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Value	Units	
PD	Total Device Dissipation	$T_a = 25^{\circ}C$ $T_c = 25^{\circ}C$	1.6 100	W W	
R _{θja}	Thermal Resistance, Junction to Ambient		77.75	°C/W	
$R_{ ext{ hetajc}}$	Thermal Resistance, Junction to Case	1.25	°C/W		

* Device mounted on minimum pad size

Ordering Information

ſ	Part Number Marking		Package	Packing Method	Remarks	
	FJB5555TM	J5555	D2-PAK	Tape & Reel		

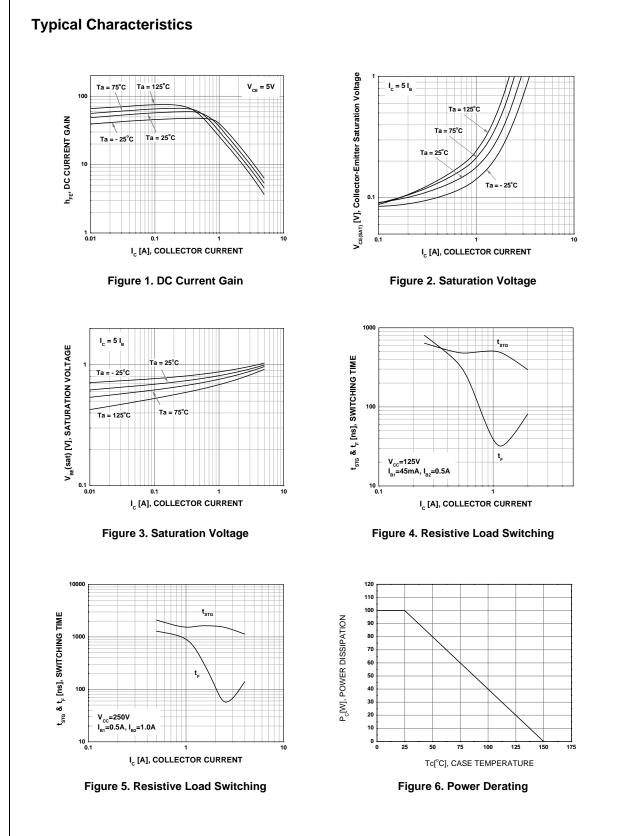
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Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =500μA, I _E =0	1050			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	400			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I _E =500μA, I _C =0	14			V
h _{FE}	DC Current Gain	V _{CE} =5V, I _C =10mA	10			
		V _{CE} =3V, I _C =0.8A	20		40	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =1A, I _B =0.2A		0.17	0.5	V
		I _C =3.5A, I _B =1.0A			1.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =3.5A, I _B =1.0A			1.2	V
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz		45		pF
t _{ON}	Turn On Time	V _{CC} =125V, I _C =0.5A I _{B1} =45mA, I _{B2} =-0.5A			1.0	μS
t _{STG}	Storage Time				1.2	μS
t _F	Fall Time	R _L =250Ω		0.3		μS
t _{ON}	Turn On Time	V _{CC} =250V, I _C =2.5A			2.0	μS
t _{STG}	Storage Time	I _{B1} =0.5A, I _{B2} =-1.0A			2.5	μS
t _F	Fall Time	R _L =100Ω			0.3	μS
EAS	Avalanche Energy	L=2mH	6			mJ

* Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%

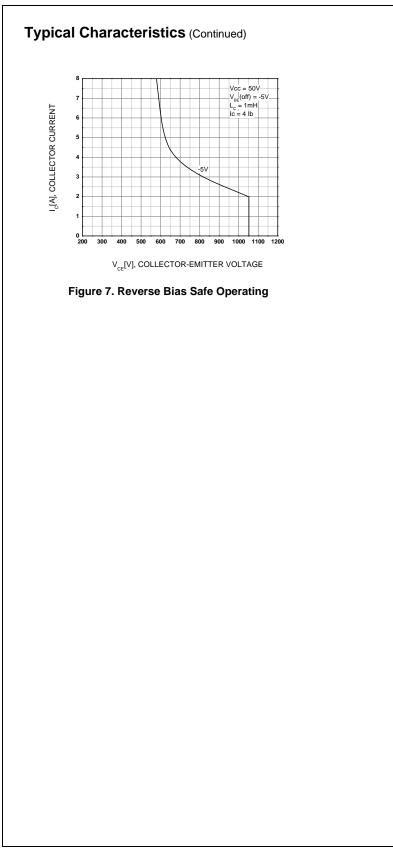
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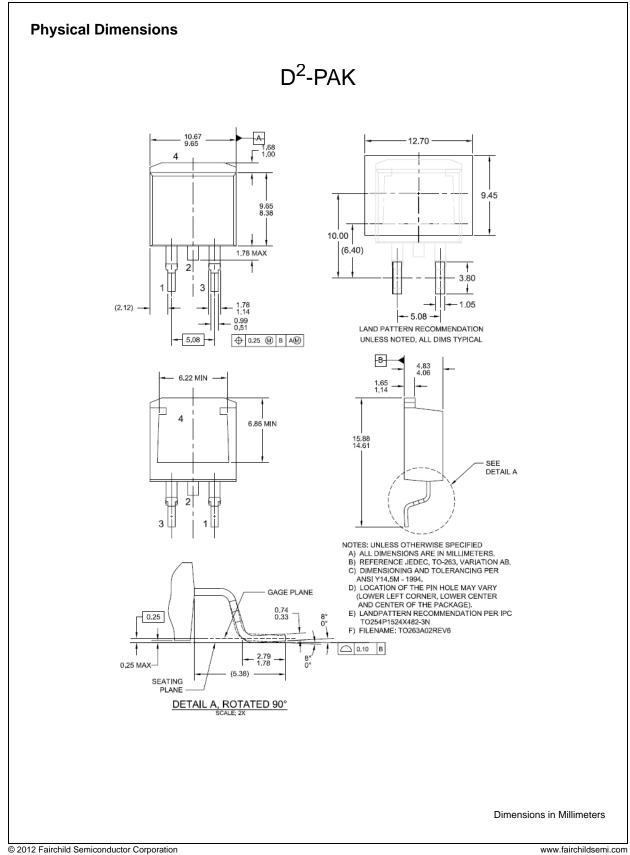


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